



## **SPECIFICATION**

• Supplier : Samsung electro-mechanics • Samsung P/N : CL10B331KB8NNNC

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 330pF, 50V, ±10%, X7R, 0603

## A. Samsung Part Number

<u>CL</u> <u>10</u> <u>B</u> <u>331</u> <u>K</u> <u>B</u> <u>8</u> <u>N</u> <u>N</u> <u>N</u> <u>C</u> ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩ ⑪

① Series	Samsung Multi-layer Ceramic Capacitor			
② Size	0603 (inch code)	L: 1.6 ± 0.1 mm	W: 0.8 ± 0.1 mm	
③ Dielectric	X7R	8 Inner electrode	Ni	
④ Capacitance	<b>330</b> pF	Termination	Cu	
⑤ Capacitance	±10 %	Plating	Sn 100% (Pb	Free)
tolerance		Product	Normal	
Rated Voltage	50 V	Special	Reserved for future use	
7 Thickness	0.8 ± 0.1 mm	Packaging	Cardboard Type, 7" reel	

## **B. Samsung Reliablility Test and Judgement condition**

	Performance	Test condition	
Capacitance	Within specified tolerance	1klb±10% 1.0±0.2Vrms	
Tan δ (DF)	0.025 max.		
Insulation	10,000Mohm or 500Mohm⋅ <i>μ</i> F	Rated Voltage 60~120 sec.	
Resistance	Whichever is Smaller		
Appearance	No abnormal exterior appearance	Microscope (×10)	
Withstanding	No dielectric breakdown or	250% of the rated voltage	
Voltage	mechanical breakdown		
Temperature	X7R		
Characterisitcs	(From -55 ℃ to 125 ℃, Capacitance change shoud be within ±15%)		
Adhesive Strength	No peeling shall be occur on the	500g⋅F, for 10±1 sec.	
of Termination	terminal electrode		
Bending Strength	Capacitance change: within ±12.5%	Bending to the limit (1mm)	
		with 1.0mm/sec.	
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder	
	is to be soldered newly	245±5℃, 3±0.3sec.	
		(preheating : 80~120℃ for 10~30sec.)	
Resistance to	Capacitance change: within ±7.5%	Solder pot : 270±5℃, 10±1sec.	
Soldering heat	Tan δ, IR : initial spec.		

	Performance	Test condition	
Vibration Test	Capacitance change: within ±5%	Amplitude : 1.5mm	
	Tan δ, IR : initial spec.	From 10Hz to 55Hz (return : 1min.)	
		2hours × 3 direction (x, y, z)	
Moisture	Capacitance change: within ±12.5%	With rated voltage	
Resistance	Tan δ : 0.05 max	40±2℃, 90~95%RH, 500+12/-0hrs	
	IR : 500Mohm or 25Mohm ⋅ μF		
	Whichever is Smaller		
High Temperature	Capacitance change: within ±12.5%	With 200% of the rated voltage	
Resistance	Tan δ : 0.05 max	Max. operating temperature	
	IR: 1000Mohm or 50Mohm $\cdot \mu$ F		
	Whichever is Smaller	1000+48/-0hrs	
Temperature	Capacitance change: within ±7.5%	1 cycle condition	
Cycling	Tan δ, IR : initial spec.	Min. operating temperatur → 25°C	
		→ Max. operating temperature → 25°C	
		5 cycle test	

## C. Recommended Soldering method :

Reflow ( Reflow Peak Temperature : 260+0/-5  $^{\circ}$ C, 10sec. Max )

<sup>\*</sup> For the more detail Specification, Please refer to the Samsung MLCC catalogue.